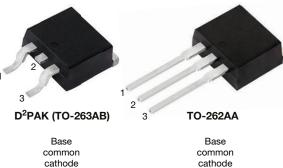
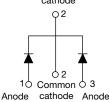
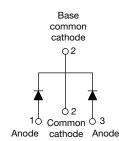


**Vishay Semiconductors** 

# High Performance Schottky Rectifier, 2 x 20 A







VS-42CTQ030S-M3

VS-42CTQ030-1-M3

PRIMARY CHARACTERISTICS					
I <sub>F(AV)</sub>	2 x 20 A				
V <sub>R</sub>	30 V				
V <sub>F</sub> at I <sub>F</sub>	0.38 V				
I <sub>RM</sub>	183 mA at 125 °C				
T <sub>J</sub> max.	150 °C				
E <sub>AS</sub>	13 mJ				
Package	D <sup>2</sup> PAK (TO-263AB), TO-262AA				
Circuit configuration	Common cathode				

## FEATURES

- 150 °C TJ operation
- Center tap configuration
- Very low forward voltage drop
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245  $^{\circ}\mathrm{C}$
- Designed and qualified according to JEDEC®-JESD 47
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

### DESCRIPTION

This center tap Schottky rectifier module has been optimized for very low forward voltage drop, with moderate leakage. The proprietary barrier technology allows for reliable operation up to 150 °C junction temperature. Typical applications are in switching power supplies, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS A	MAJOR RATINGS AND CHARACTERISTICS					
SYMBOL	CHARACTERISTICS	VALUES	UNITS			
I <sub>F(AV)</sub>	Rectangular waveform	40	А			
V <sub>RRM</sub>		30	V			
I <sub>FSM</sub>	t <sub>p</sub> = 5 μs sine	1100	А			
V <sub>F</sub>	20 A <sub>pk</sub> , T <sub>J</sub> = 125 °C (per leg)	0.38	V			
TJ	Range	-55 to +150	°C			

VOLTAGE RATINGS			
PARAMETER	SYMBOL	VS-42CTQ030S-M3 VS-42CTQ030-1-M3	UNITS
Maximum DC reverse voltage	V <sub>R</sub>	30	V
Maximum working peak reverse voltage	V <sub>RWM</sub>	30	V

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ABSOLUTE MAXIMU	JM RATING	GS				
PARAMETER		SYMBOL	TEST COND	ITIONS	VALUES	UNITS
Maximum average	per leg				20	
forward current See fig. 5	per device	I <sub>F(AV)</sub>	50 % duty cycle at T <sub>C</sub> = 121 °(	C, rectangular waveform	40	А
Maximum peak one cycle no	on-repetitive		5 µs sine or 3 µs rect. pulse	Following any rated load	1100	A
surge current per leg See fig. 7		I <sub>FSM</sub>	10 ms sine or 6 ms rect. pulse	condition and with rated V <sub>RRM</sub> applied	360	
Non-repetitive avalanche en	ergy per leg	E <sub>AS</sub>	T <sub>J</sub> = 25 °C, I <sub>AS</sub> = 3 A, L = 2.90 mH		13	mJ
Repetitive avalanche current per leg		I <sub>AR</sub>	Current decaying linearly to zero in 1 $\mu$ s Frequency limited by T <sub>J</sub> maximum V <sub>A</sub> = 1.5 x V <sub>R</sub> typical		3	А

ELECTRICAL SPECIFICATION	S				
PARAMETER	SYMBOL	TEST CO	NDITIONS	VALUES	UNITS
		20 A	T <sub>J</sub> = 25 °C	0.48	
Maximum forward voltage drop per leg	V <sub>FM</sub> <sup>(1)</sup>	40 A	1j=25 0	0.57	v
See fig. 1	VFM ("	20 A	T <sub>.1</sub> = 125 °C	0.38	
		40 A	1j = 125 C	0.51	
Maximum reverse leakage current per leg	I <sub>RM</sub> <sup>(1)</sup>	T <sub>J</sub> = 25 °C		3	mA
See fig. 2	IRM (')	T <sub>J</sub> = 125 °C	V <sub>R</sub> = Rated V <sub>R</sub>	183	
Threshold Voltage	V <sub>F(TO)</sub>	T _T movimum		0.22	V
Forward slope resistance	r <sub>t</sub>	T <sub>J</sub> =T <sub>J</sub> maximum		6.76	mΩ
Maximum junction capacitance per leg	CT	$V_R = 5 V_{DC}$ (test signal rang	2840	pF	
Typical series inductance per leg	L <sub>S</sub>	Measured lead to lead 5 m	8.0	nH	
Maximum voltage rate of change	dV/dt	Rated V <sub>R</sub>	10 000	V/µs	

### Note

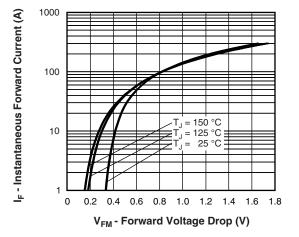
 $^{(1)}\,$  Pulse width < 300  $\mu s,$  duty cycle < 2 %

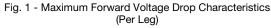
THERMAL - MECHA	NICAL SP	ECIFICAT	IONS		
PARAMETER		SYMBOL	SYMBOL TEST CONDITIONS		UNITS
Maximum junction and stora temperature range	ige	T <sub>J</sub> , T <sub>Stg</sub>		-55 to 150	°C
Maximum thermal resistance, junction to case per leg		Р	DC operation	2.0	
Maximum thermal resistance, junction to case per package		R <sub>thJC</sub>	Do operation	1.0	°C/W
Typical thermal resistance, case to heatsink		R <sub>thCS</sub>	Mounting surface, smooth and greased	0.50	
Approximate weight				2	g
Approximate weight				0.07	oz.
Mounting torque	minimum			6 (5)	kgf ⋅ cm
Mounting torque	maximum			12 (10)	(lbf · in)
Marking dovice			Case style D <sup>2</sup> PAK (TO-263AB)	42CTC	2030S
Marking device			Case style TO-262AA	42CTC	030-1

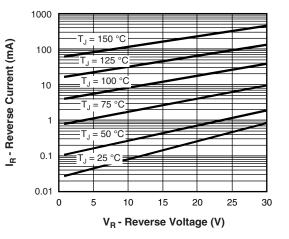
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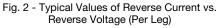


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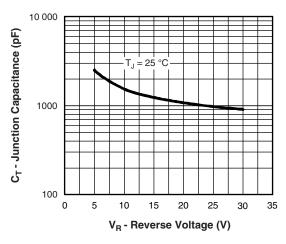
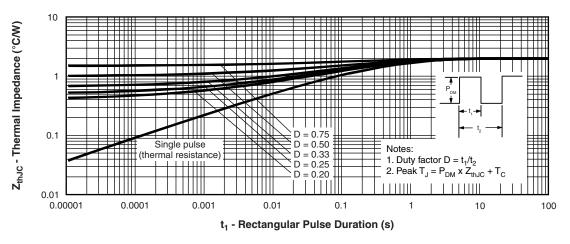


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage (Per Leg)



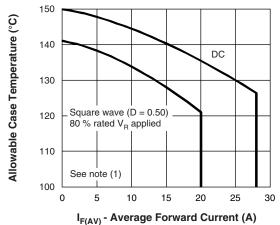


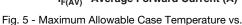
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Average Forward Current (Per Leg)

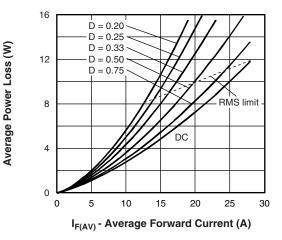


Fig. 6 - Forward Power Loss Characteristics (Per Leg)

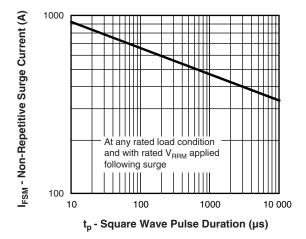


Fig. 7 - Maximum Non-Repetitive Surge Current (Per Leg)

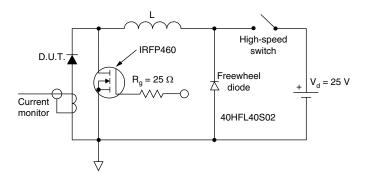


Fig. 8 - Unclamped Inductive Test Circuit

#### Note

<sup>(1)</sup> Formula used:  $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$ ;

Pd = forward power loss =  $I_{F(AV)} \times V_{FM}$  at ( $I_{F(AV)}/D$ ) (see fig. 6);  $Pd_{REV}$  = inverse power loss =  $V_{R1} \times I_R (1 - D)$ ;  $I_R$  at  $V_{R1}$  = 10 V

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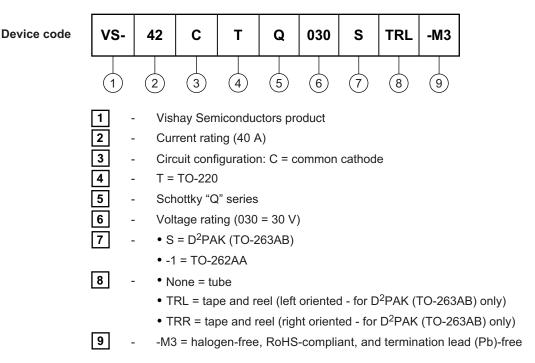
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## **Vishay Semiconductors**

**ORDERING INFORMATION TABLE** 



ORDERING INFORMATION						
PREFERRED P/N	BASE QUANTITY	PACKAGING DESCRIPTION				
VS-42CTQ030S-M3	50	Antistatic plastic tubes				
VS-42CTQ030STRL-M3	800	13" diameter plastic tape and reel				
VS-42CTQ030STRR-M3	800	13" diameter plastic tape and reel				
VS-42CTQ030-1-M3	50	Antistatic plastic tubes				

	LINKS TO RELATED	DOCUMENTS
Dimensions	D <sup>2</sup> PAK (TO-263AB)	www.vishay.com/doc?96164
Dimensions	TO-262AA	www.vishay.com/doc?96165
Port marking information	D <sup>2</sup> PAK (TO-263AB)	www.vishay.com/doc?95444
Part marking information	TO-262AA	www.vishay.com/doc?95443
Packaging information		www.vishay.com/doc?96424

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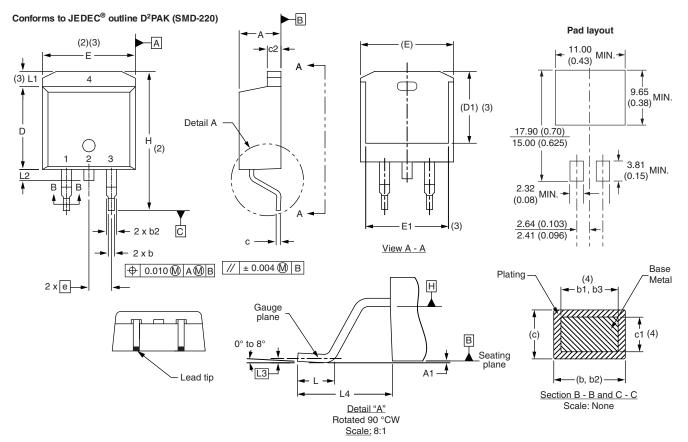


# **Outline Dimensions**

**Vishay Semiconductors** 



### **DIMENSIONS** in millimeters and inches



SYMBOL	MILLIM	IETERS	INC	HES	NOTES	SYMBOL	MILLIM	IETERS	INC	HES	NOTES
STMBOL	MIN.	MAX.	MIN.	MAX.	NOTES	STINDUL	MIN.	MAX.	MIN.	MAX.	NOTES
A	4.06	4.83	0.160	0.190		D1	6.86	8.00	0.270	0.315	3
A1	0.00	0.254	0.000	0.010		E	9.65	10.67	0.380	0.420	2, 3
b	0.51	0.99	0.020	0.039		E1	7.90	8.80	0.311	0.346	3
b1	0.51	0.89	0.020	0.035	4	е	2.54	BSC	0.100	) BSC	
b2	1.14	1.78	0.045	0.070		Н	14.61	15.88	0.575	0.625	
b3	1.14	1.73	0.045	0.068	4	L	1.78	2.79	0.070	0.110	
с	0.38	0.74	0.015	0.029		L1	-	1.65	-	0.066	3
c1	0.38	0.58	0.015	0.023	4	L2	1.27	1.78	0.050	0.070	
c2	1.14	1.65	0.045	0.065		L3	0.25	BSC	0.010	) BSC	
D	8.51	9.65	0.335	0.380	2	L4	4.78	5.28	0.188	0.208	

#### Notes

 $^{(1)}\,$  Dimensioning and tolerancing per ASME Y14.5 M-1994  $\,$ 

(2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body

<sup>(3)</sup> Thermal pad contour optional within dimension E, L1, D1 and E1

<sup>(4)</sup> Dimension b1 and c1 apply to base metal only

<sup>(5)</sup> Datum A and B to be determined at datum plane H

<sup>(6)</sup> Controlling dimension: inch

<sup>(7)</sup> Outline conforms to JEDEC<sup>®</sup> outline TO-263AB

Revision: 08-Jul-15

1

Document Number: 95046

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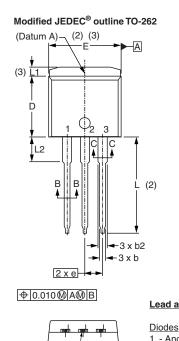


# **Outline Dimensions**

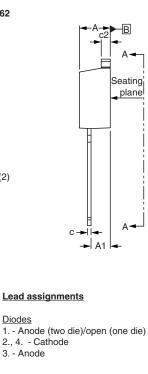
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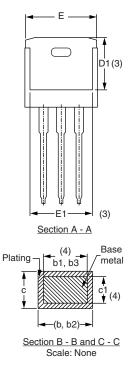
**TO-262** 

### **DIMENSIONS** in millimeters and inches



Lead tip





SYMBOL	MILLIN	IETERS	INC	INCHES			
STINDUL	MIN.	MAX.	MIN.	MAX.	NOTES		
А	4.06	4.83	0.160	0.190			
A1	2.03	3.02	0.080	0.119			
b	0.51	0.99	0.020	0.039			
b1	0.51	0.89	0.020	0.035	4		
b2	1.14	1.78	0.045	0.070			
b3	1.14	1.73	0.045	0.068	4		
С	0.38	0.74	0.015	0.029			
c1	0.38	0.58	0.015	0.023	4		
c2 1.14	2 1.14	1.65	0.045	0.065			
D	8.51	9.65	0.335	0.380	2		
D1	6.86	8.00	0.270	0.315	3		
E	9.65	10.67	0.380	0.420	2, 3		
E1	7.90	8.80	0.311	0.346	3		
е	2.54 BSC		0.100	BSC			
L	13.46	14.10	0.530	0.555			
L1	-	1.65	-	0.065	3		
L2	3.36	3.71	0.132	0.146			

3. - Anode

#### Notes

<sup>(1)</sup> Dimensioning and tolerancing as per ASME Y14.5M-1994

<sup>(2)</sup> Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body

<sup>(3)</sup> Thermal pad contour optional within dimension E, L1, D1 and E1

(4) Dimension b1 and c1 apply to base metal only

<sup>(5)</sup> Controlling dimension: inches

(6) Outline conform to JEDEC TO-262 except A1 (maximum), b (minimum), D1 (minimum) and L2 where dimensions derived the actual package outline

Revision: 11-Jul-2019

Document Number: 95419

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